



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Yi Ding
Assignee: Mosel Vitelic, Inc.
Title: Nonvolatile Memory Cell With Multiple Floating Gates Formed After the Select Gate
Application No.: 10/631,941 Filing Date: July 30, 2003
Examiner: Unknown Group Art Unit: Unassigned
Docket No.: M-15171 US

San Jose, California
April 15, 2004

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR § 1.97(b)

Dear Sir:

Pursuant to 37 CFR § 1.56, § 1.97 and § 1.98, the documents listed on the accompanying form PTO-1449 are called to the attention of the Examiner for the above patent application. Copies of these documents are enclosed except for United States Patents and United States Published Patent Applications.

Citation of these documents shall not be construed as:

1. an admission that the documents are necessarily prior art with respect to the instant invention;
2. a representation that a search has been made, other than as described above; or
3. an admission that the information cited herein is, or is considered to be material to patentability as defined in § 1.56(b).

No fee is believed to be required. If a fee is required for this Information Disclosure Statement, please charge the fee to Deposit Account No. 50-2257. This paper is being submitted in duplicate.

I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class Mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on April 15, 2004.

Michael Shenker 4-15-04

Attorney for Applicant Date of Signature

Respectfully submitted,

Michael Shenker
Michael Shenker
Attorney for Applicant(s)
Reg. No. 34,250

LAW OFFICES OF
MacPherson, Kwok, Chen &
Held LLP
1762 Technology Drive, Suite 220
San Jose, CA 95110
Telephone (408) 392-0530
Fax (408) 392-9262

U.S. Department of Commerce, Patent and Trademark Office				Atty Docket No.	Serial No.		
				M-15171 US	10/631,941		
INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Applicant			
(Use several sheets if necessary)				Yi Ding			
				Filing Date	Group		
				July 30, 2003	Unassigned		
U.S. Patent Documents							
*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
	AA	6,420,231	16 Jul. 2002	Harari et al.			
	AB	2003/0218908 A1	27 Nov. 2003	Park et al.			
	AC	2004/0004863 A1	8 Jan. 2004	Wang			
	AD						
	AE						
	AF						
	AG						
	AH						
Foreign Patent Documents							
		Document	Date	Country	Class	Subclass	Translation
	AI	EP 0 938 098 A2	25 Aug. 1999	Europe			Yes
	AJ						No
	AK						
	AL						
OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)							
	AM	United States Patent Application No. 10/798,475, entitled "Fabrication of Conductive Lines Interconnecting Conductive Gates in Nonvolatile Memories and Non-Volatile Memory Structures," Filed on March 10, 2004; Attorney Docket No. M-15296 US.					
	AN	United States Patent Application No. 10/797,972, entitled "Fabrication of Conductive Lines Interconnecting First Conductive Gates in Nonvolatile Memories Having Second Conductive Gates Provided By Conductive Gates Lines, Wherein The Adjacent Conductive Gate Lines For The Adjacent Columns Are Spaced From Each Other, And Non-Volatile Memory Structures," Filed on March 10, 2004; Attorney Docket No. M-15297 US.					
	AO						
	AP						
Examiner		Date Considered					
<p>*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.</p>							

